

### INCHANGE SEMICONDUCTOR

# isc N-Channel MOSFET Transistor

## IPW60R190P6

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### • FEATURES

- Static drain-source on-resistance:  $R_{DS}(on) \leqslant 190 m_{\Omega}$
- · Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

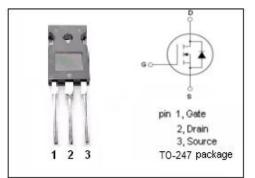
· Fast switching

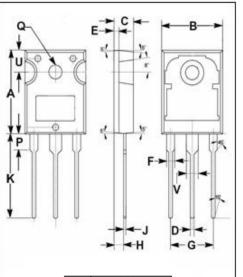
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

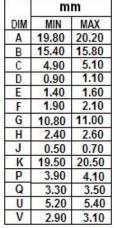
SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	600	V
$V_{GS}$	Gate-Source Voltage	±20	V
ID	Drain Current-Continuous	20.2	А
I <sub>DM</sub>	Drain Current-Single Pulsed 57		A
PD	Total Dissipation @Tc=25°C	151	W
Tj	Max. Operating Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~150	°C

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(j-c)	Channel-to-case thermal resistance	0.83	°C <b>/W</b>
Rth(j-a)	Channel-to-ambient thermal resistance	62	℃/W









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### **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA	600			V
$V_{GS(th)}$	Gate Threshold Voltage	VDS=VGS; I <sub>D</sub> =0.63mA	3.5		4.5	V
$R_{\text{DS(on)}}$	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =7.6A			190	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = 20V			0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =600V; V <sub>GS</sub> = 0V			1	μA
$V_{\text{SD}}$	Diode forward voltage	I <sub>F</sub> =9.5A, V <sub>GS</sub> = 0V				V

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